

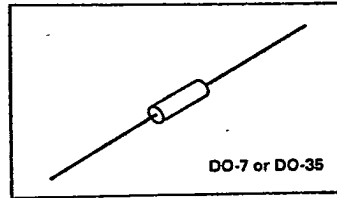
2514096 CRIMSON SEMICONDUCTOR INC

99D 00352

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7-01-09

SILICON DIODES



Type	Case	P.I.V. Volts	Min. Forward Current at 1V		Reverse Current at 25°C μA	Reverse Voltage	Maximum Reverse Current at Temp.		Cap. pF	Re-cov. Time		Power Dissipation mW
			mA	μA			μA	°C		nS	ns	
1N456	DO35	30	40		.025	25	5	150				250
1N456A	DO35	30	100		.025	25	5	150				250
1N457	DO35	70	20		.025	60	5	150				250
1N457A	DO35	70	100		.025	60	5	150				250
1N458	DO35	150	7		.025	125	5	150				250
1N458A	DO35	150	100		.025	125	5	150				250
1N461	DO35	30	15		.5	25	30	150				250
1N461A	DO35	30	100		.5	25	30	150				250
1N462	DO35	70	5		.5	60	30	150				250
1N462A	DO35	70	100		.5	60	30	150				250
1N463	DO7	200	1		.5	175	30	150				250
1N464	DO35	150	3		.5	125	30	150				250
1N464A	DO7	150	100		.5	125	30	150				250
1N482	DO35	40	100 @ 1.1V		.25	30	30	150				250
1N482A	DO35	40	100		.025	30	15	150				250
1N482B	DO35	40	100		.025	30	5	150				250
1N483	DO35	70	100 @ 1.1V		.25	60	30	150				250
1N483A	DO35	70	100		.025	60	15	150				250
1N483B	DO35	80	100		.025	60	5	150				250
1N484	DO35	130	100 @ 1.1V		.25	125	30	150				250
1N484A	DO35	130	100		.025	125	15	150				250
1N484B	DO35	130	100		.025	125	5	150				250
1N660	DO7	100	6		.5	100	50	100	2.7	300		200
1N662A	DO7	100	100		10	200				300		250
1N914	DO35	100	10		.025	20	50	150	4		4	250
1N914A	DO35	100	20		.025	20	50	150	4		4	250
1N914B	DO35	100	100		.025	20	50	150	4		4	250